IBM Docket No.: BUR920030052US1

Declaration and Power of Attorney for Patent Application

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled: STRUCTURE FOR MEASUREMENT OF CAPACITANCE OF ULTRA-THIN DIELECTRICS

the specification of which (che	eck one)		
X is attache	ed hereto.		
was filed	on as A [pplication Serial No.	and was amended on
I hereby state that I have revie by any amendment referred to	wed and understand the cont ว above.	ents of the above-identified spec	cification, including the claims, as amended
I acknowledge the duty to disc of Federal Regulations, §1.56	lose information which is mat	terial to the patentability of this a	oplication in accordance with Title 37, Code
I hereby claim foreign priority certificate listed below and have that of the application on which	e also identified below any fo	ed States Code, §119 of any fo reign application for patent or inv	reign application(s) for patent or inventor's entor's certificate having a filing date before
Prior Foreign Applic	cation(s):		
Number	Country	Day/Month/Year	Priority Claimed
the first paragraph of Title 35,	claims of this application is no United States Code, §112, I in Title 37, Code of Federa	ot disclosed in the prior United Si I acknowledge the duty to disclo I Regulations, §1.56 which occ	plication(s) listed below and, insofar as the tates application in the manner provided by se information material to the patentability curred between the filing date of the prior
Prior U.S. Application	ons:		
Serial No.		Filing Date	Status
are believed to be true; and full made are punishable by fine of	urther that these statements v or imprisonment, or both, und	were made with the knowledge t	statements made on information and belief hat willful false statements and the like so he United States Code and that such willful n.
the Patent and Trademark Off Richard A. Henkler, Reg. No. Walsh, Reg. No. 26,516; Chi	fice connected therewith: Ant o. 39,220; Richard M. Koti ristopher A. Hughes, Reg. N	thony J. Canale, Reg. No. 51.52 ulak, Reg. No. 27,712; Willia	his application and transact all business in 26; Mark F. Chadurjian, Reg. No. 30,739; m D. Sabo, Reg. No. 27,465; Robert A. No. 26,279; and Joseph C. Redmond, Jr., No. 37,629).
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IBM Docket No.: BUR920030052US1

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Page 2 of 2